TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT Process) (Bias Resistor built-in Transistor)

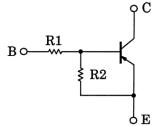
RN2907, RN2908, RN2909

Switching, Inverter Circuit, Interface Circuit and Driver Circuit

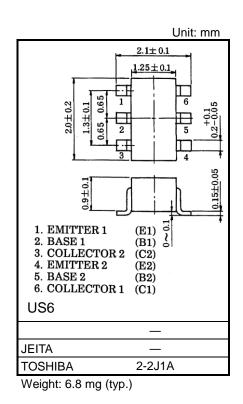
- AEC-Q101 Qualified (Note1)
- Including two devices in US6 (ultra super mini type with 6 leads)
- With built-in bias resistors.
- Simplify circuit design
- Reduce a quantity of parts and manufacturing process and miniaturize equipment.
- Various resistance values are available to suit various circuit designs.
- Complementary to RN1907 to RN1909

Note1: For detail information, please contact to our sales.

Equivalent Circuit and Bias Resistor Values



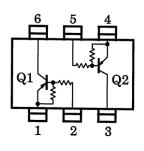
Part No.	R1 (kΩ)	R2 (kΩ)
RN2907	10	47
RN2908	22	47
RN2909	47	22



Absolute Maximum Ratings (Ta = 25°C) (Q1, Q2 Common)

Characteris	tic	Symbol	Rating	Unit	
Collector-base voltage	DN0007 to 0000	VCBO	-50	V	
Collector-emitter voltage	RN2907 to 2909	VCEO	-50	V	
	RN2907	VEBO	-6	V	
Emitter-base voltage	RN2908		-7		
	RN2909		-15		
Collector current		IC	-100	mA	
Collector power dissipation	RN2907 to 2909	Pc*	200	mW	
Junction temperature	KIN2907 10 2909	Tj	150	°C	
Storage temperature range		T _{stg}	-55 to 150	°C	

Equivalent Circuit (Top View)



Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

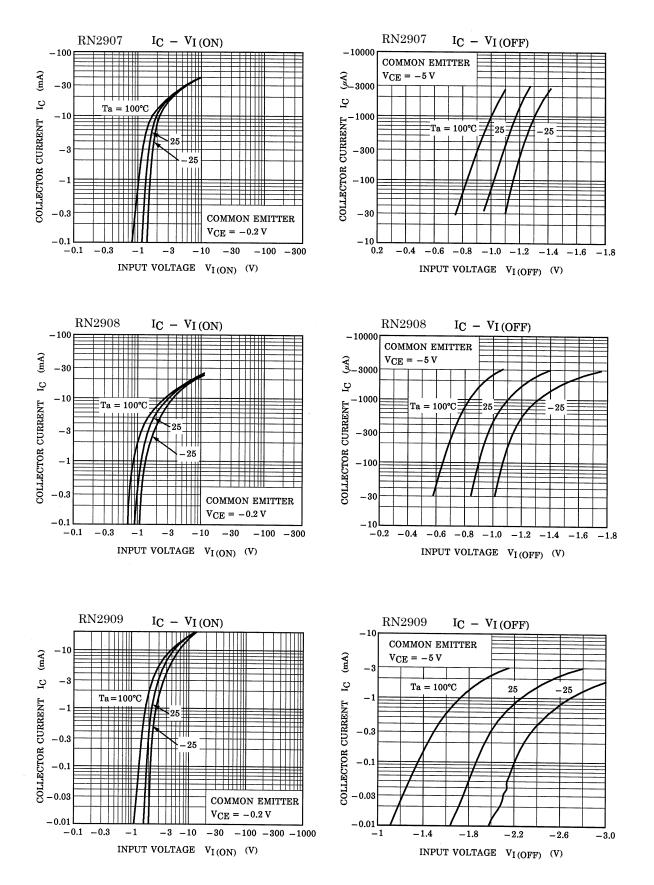
* : Total rating

Electrical Characteristics (Ta = 25°C) (Q1, Q2 Common)

Charact	teristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	DN0007 to 0000	Ісво	V _{CB} = -50 V, I _E = 0 mA	_	_	-100	nA
	RN2907 to 2909	ICEO	Vce = −50 V, IB = 0 mA	_	_	-500	nA
Emitter cut-off current	RN2907	IEBO	VEB = -6 V, IC = 0 mA	-0.081	_	-0.15	mA
	RN2908		VEB = −7 V, IC = 0 mA	-0.078	_	-0.145	
	RN2909		V _{EB} = −15 V, I _C = 0 mA	-0.167	_	-0.311	
	RN2907	hFE	V _{CE} = -5 V, I _C = -10 mA	80	_	_	
DC current gain	RN2908			80	_	_	
	RN2909			70	_	_	
Collector-emitter saturation voltage	RN2907 to 2909	VCE (sat)	IC = -5 mA, IB = -0.25 mA	_	-0.1	-0.3	V
Input voltage (ON)	RN2907	VI (ON)	VCE = -0.2 V, IC = -5 mA	-0.7	_	-1.8	V
	RN2908			-1.0	_	-2.6	
	RN2909			-2.2	_	-5.8	
	RN2907	VI (OFF)	$V_{CE} = -5 V, I_C = -0.1 mA$	-0.5	_	-1.0	V
Input voltage (OFF)	RN2908			-0.6	_	-1.16	
	RN2909			-1.5	_	-2.6	
Translation frequency	RN2907 to 2909	f⊤	V _{CE} = -10 V, I _C = -5mA	_	200	_	MHz
Collector output capacitance	RN2907 to 2909	C _{ob}	V _{CB} = -10 V, I _E = 0 mA, f = 1 MHz	_	3	6	pF
	RN2907	R1	_	7	10	13	
Input resistor	RN2908			15.4	22	28.6	kΩ
	RN2909			32.9	47	61.1	
Resistor ratio	RN2907	R1/R2	_	0.191	0.213	0.232	
	RN2908			0.421	0.468	0.515	-
	RN2909			1.92	2.14	2.35	1

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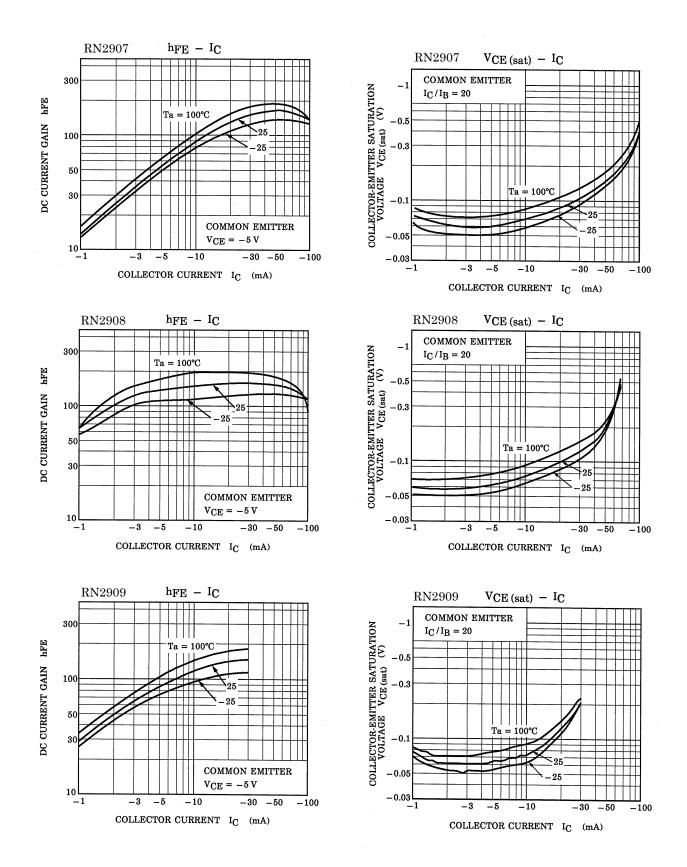
Characteristics Curves (Q1, Q2 Common)



The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

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Characteristics Curves (Q1, Q2 Common)



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Marking

Part No.	Marking
RN2907	Part No.(abbreviation code)
RN2908	Part No.(abbreviation code)
RN2909	Part No.(abbreviation code)

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